Electromagnetic Compatibility (EMC)

Basic knowledge used in EMC

Agenda

Circuit Analysis

- Use of Network Theory
- Capacitor Coupling
- Inductor Coupling
- Discrimination
- Practical Model of Component and Frequency Response
- Common mode and Differential mode
- Near Field and Far Field
- Antenna Effect
- Transmission Line Analysis



Circuit analysis assumes the following
 All *electric fields* are confined to the interiors of *capacitors*.

- All magnetic fields are confined to the interiors of inductors.
- Dimensions of the circuits are very small compared to the wavelength under consideration.

Capacitor Coupling

Vs ~

 $C1 \ge$

C2

≤Rī.

Noise voltage : $V_N = \frac{j\omega[C_{12}/(C_{12}+C_2)]}{j\omega+1/R_L(C_{12}+C_2)} \cdot V_s$ for $R_L << \frac{1}{j\omega(C_{12}+C_2)}$

$$V_N = jwR_L C_{12} V_S$$

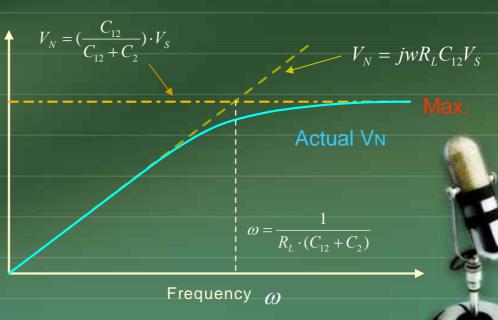
- Assuming the voltage and frequency of the noise source cannot be changed
 - Decreasing capacitance C₁₂
 - Let receiver circuit operate at a lower resistance level R₁

Capacitor Coupling

Noise voltage $V_N = \frac{j\omega[C_{12}/(C_{12}+C_2)]}{j\omega+1/R(C_{12}+C_2)} V_S$ for $R_L >> \frac{1}{j\omega(C_1+C_2)}$

$$V_N = V_{N(\text{max})} = (\frac{C_{12}}{C_{12} + C_2}) \cdot V_S$$

Noise Voltage Vn



A A

Capacitor Coupling With Shielding

S

CSG

Noise voltage :

$$= (\frac{C_{12}}{C_{12} + C_{2G} + C_{2S}}) \cdot b$$

C12 depends on the length of conductor 2 that extends beyond the shield.

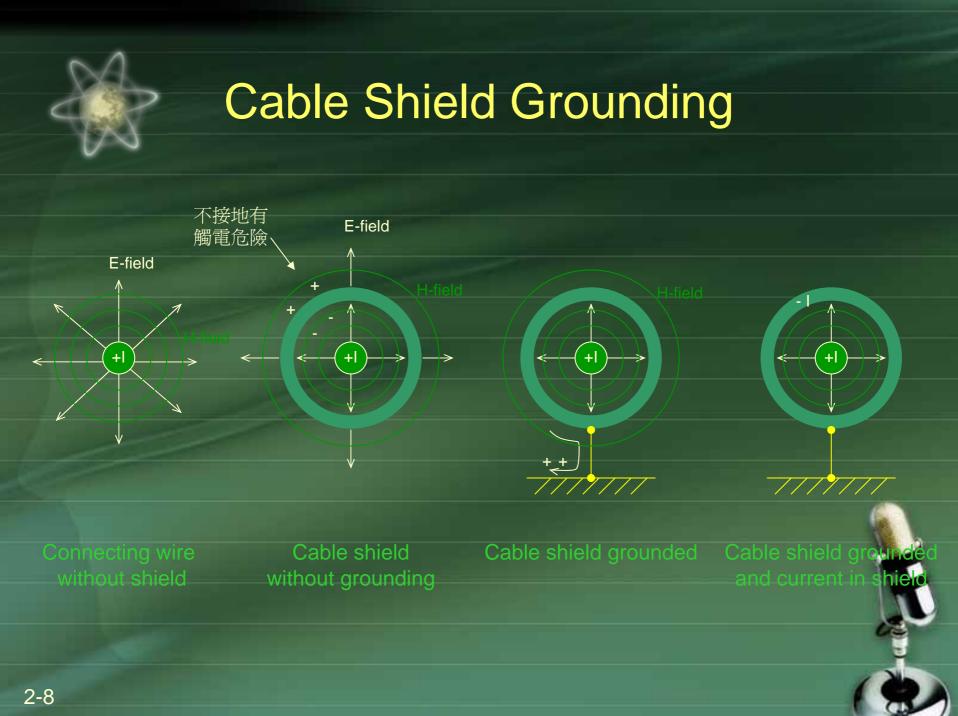
 V_N

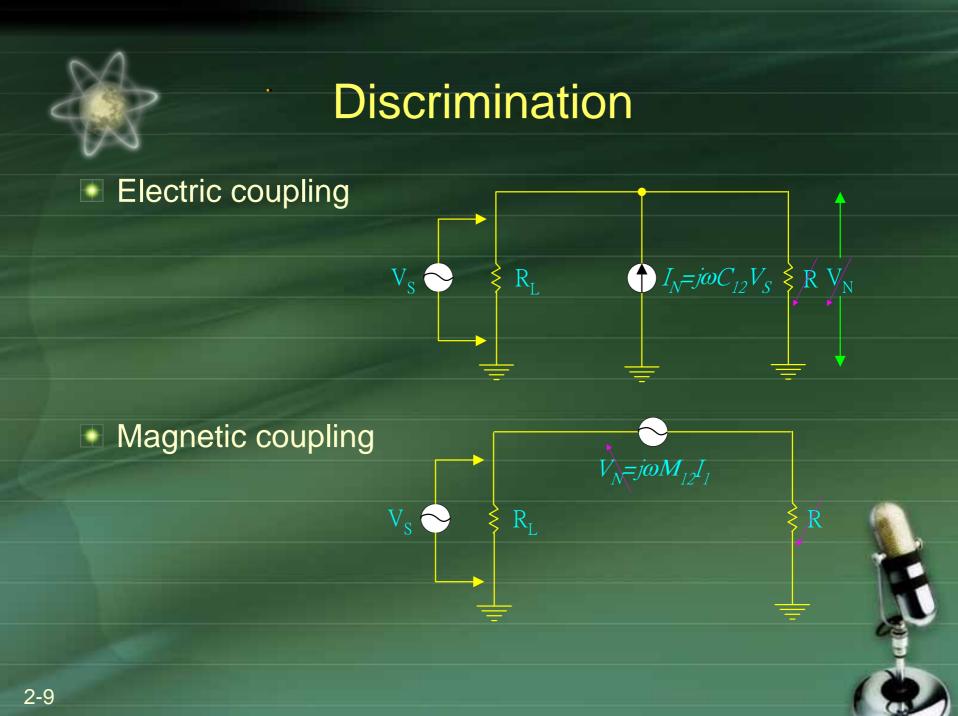
- For good electric field shielding, it is therefore necessary
 - to minimize the length of the center conductor extending beyond the shield.
 - to provide a good ground on the shield.
 Vs

Inductor Coupling

Noise voltage : $V_N = j\omega BA \cos \theta = j\omega M_{12} \cdot I_{12}$

- B is the rms value of the sinusoidally varying flex density produced by current I in circuit 1.
- A is the area of closed loop in circuit 2.
- M_{12} is the mutual inductance between conductor 1 and 2.
- Strategies
 - Decreasing loop area \vec{A}
 - Twisted line, proper grounding, shielding ...
 - Decreasing flux density \vec{B} or mutual inductance M_{12}
 - Physical separation of the circuits, current flowing in the twisted pair...







Circuit Analysis Practical Model of Component and Frequency Response Capacitor Inductor Common mode and Differential mode Near Field and Far Field Antenna Effect Transmission Line Analysis

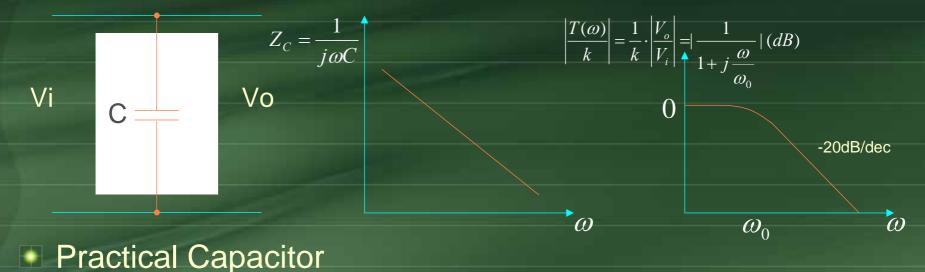
Practical Model of Component Capacitor Measurement setup **Practical Capacitor** Тх Rx Z_{C} С ω ω_r Z_{C} С Τх Rx ω 2-11

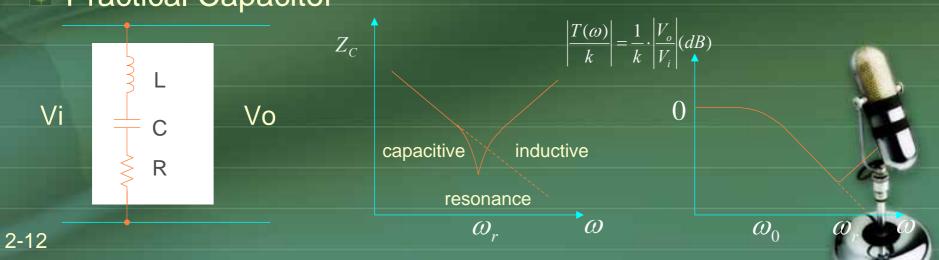
Practical Model of Component Capacitor

Ideal Capacitor

Impedance

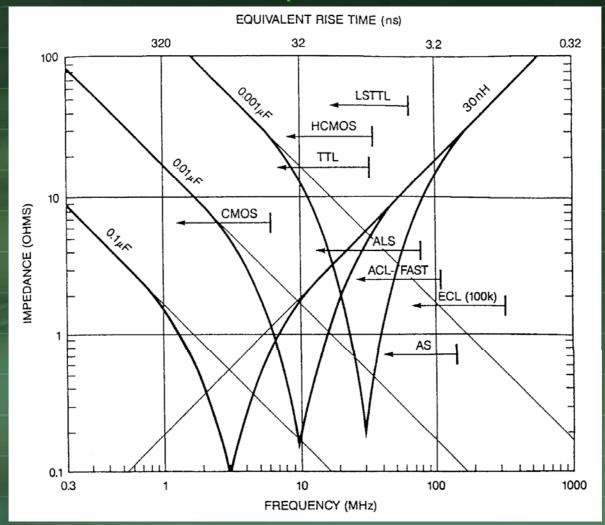
Transfer Function





Practical Model of Component

Capacitor



Impedance of various value decoupling capacitors in series with 30nH of inductance



Practical Model of Component Capacitor

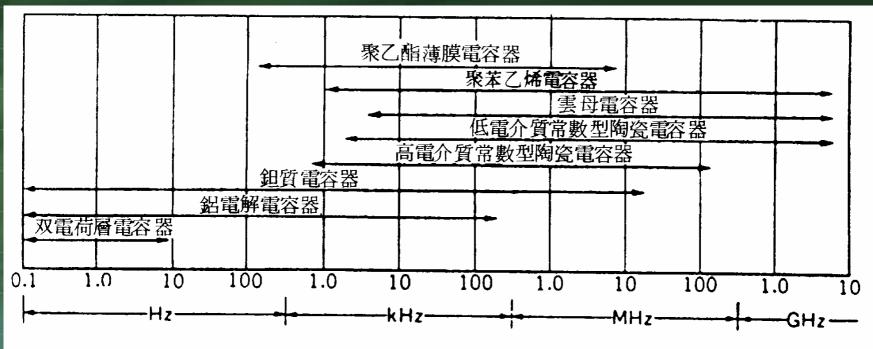
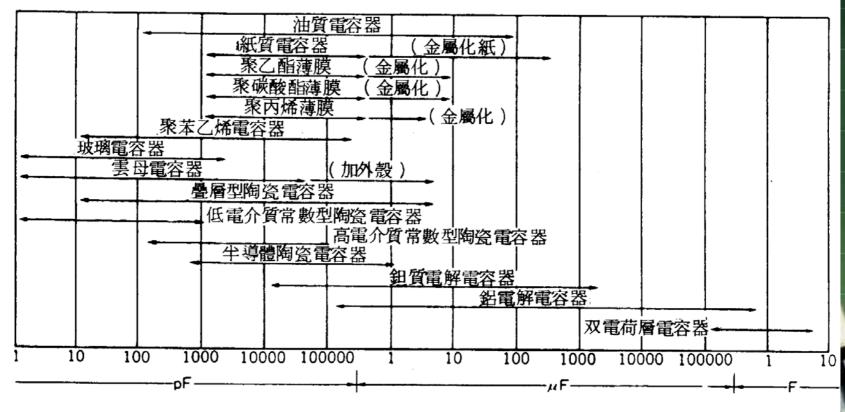
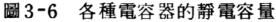


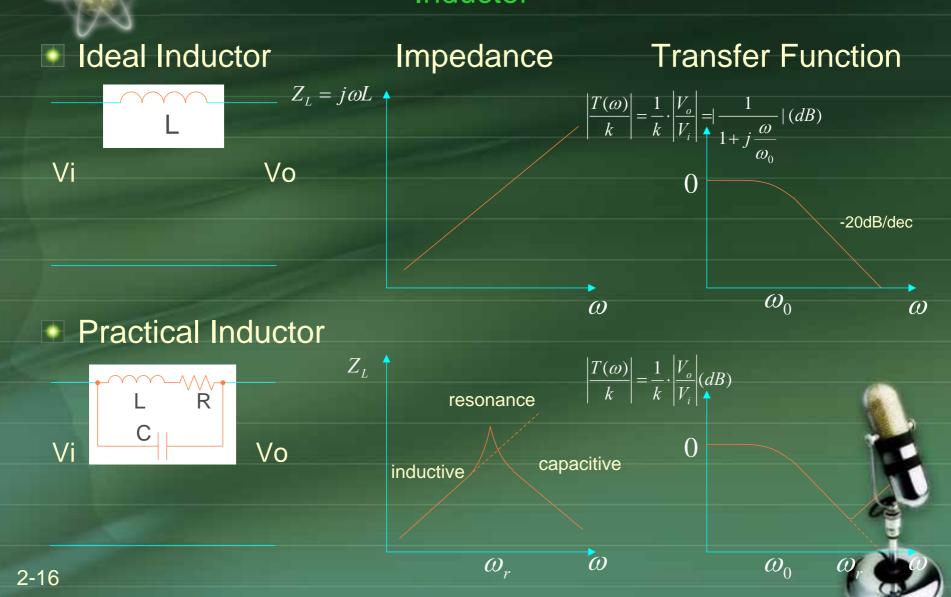
圖 3-5 主要電容器的頻率特性

Practical Model of Component Capacitor





Practical Model of Component Inductor

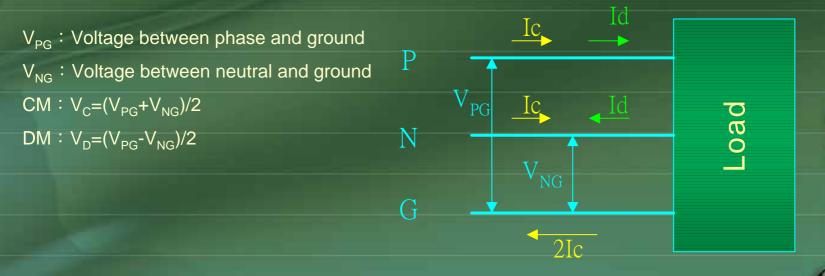




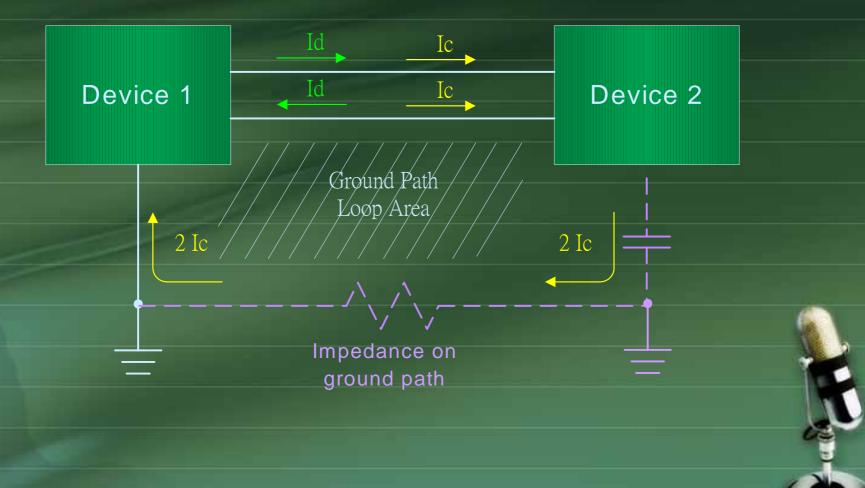
Circuit Analysis Practical Model of Component and **Frequency Response** Capacitor Inductor Common mode and Differential mode Near Field and Far Field Antenna Effect Transmission Line Analysis

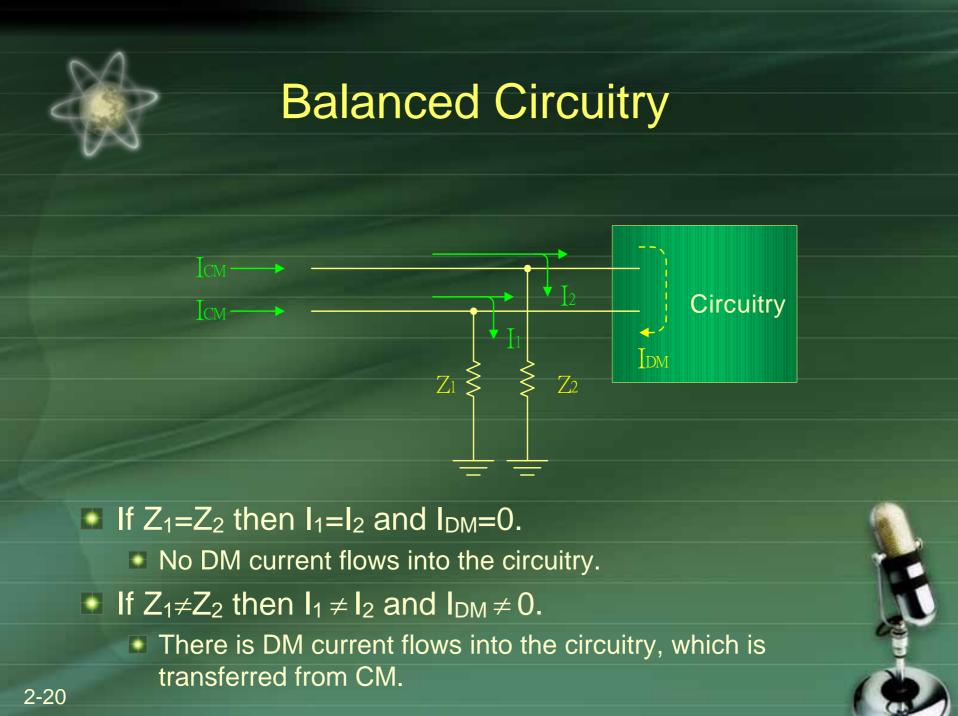
Common Mode and Differential Mode

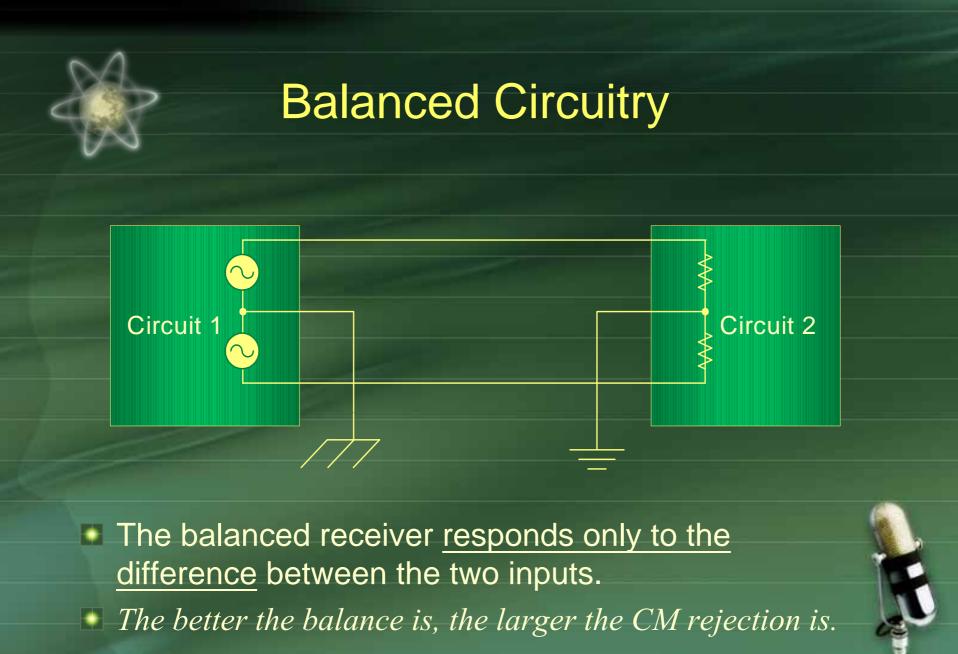
 Common-Mode(CM) – Balance Circuit
 Cause of ground impedance in design or measurement system
 Differential-Mode(DM) – Unbalance Circuit
 Cause of internal circuit operation or unbalance



Common Mode and Differential Mode







Balanced Circuitry Example -- Differential Amplifiers

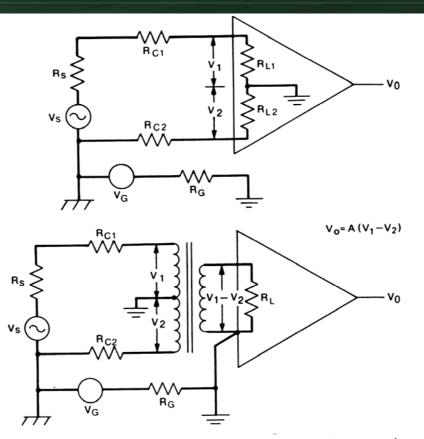
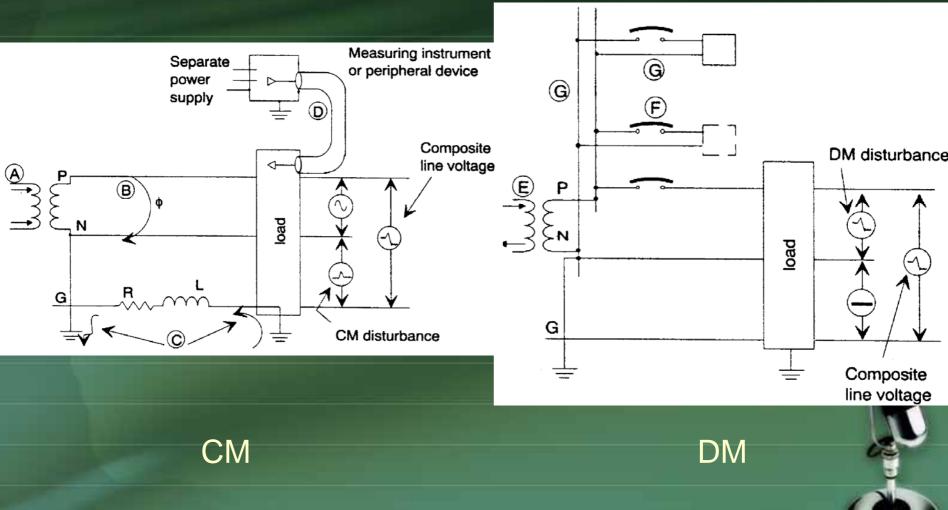


Figure 3-35. A differential amplifier—or a single-ended amplifier with transformer—can be used to reduce the effects of a common-mode noise voltage.

A single-ended (or unbalanced) amplifier with transformer can be used to simulate the performance of a balanced amplifier.

Using a transformer

CM / DM Example





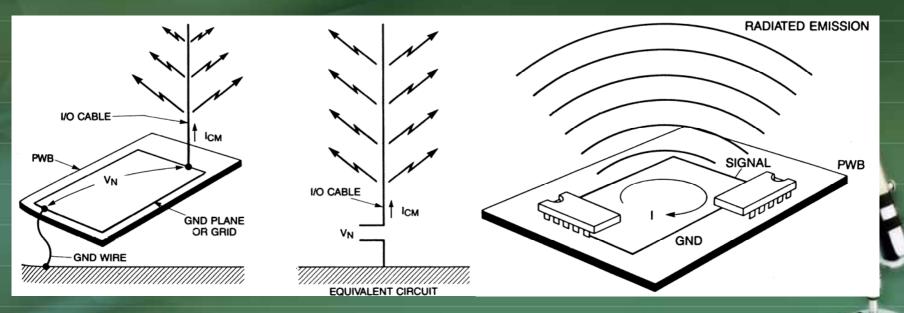
CM / DM Radiation

CM radiation

- A low current and high voltage source, like a rod or straight antenna.
- ▶ 用電場探棒量

DM radiation

- A high current and low voltage source, like a loop antenna.
 - 用磁場探棒量





Circuit Analysis Practical Model of Component and **Frequency Response** Capacitor Inductor Common mode and Differential mode Near Field and Far Field Antenna Effect Transmission Line Analysis

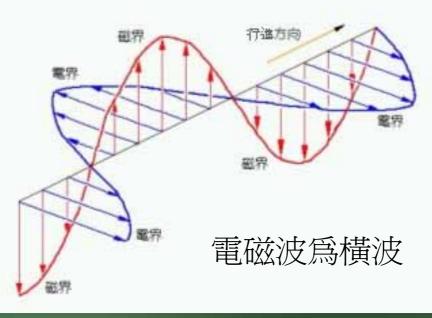


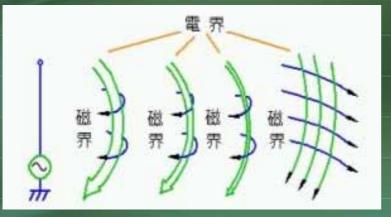
💽 Wave Impedance : Z

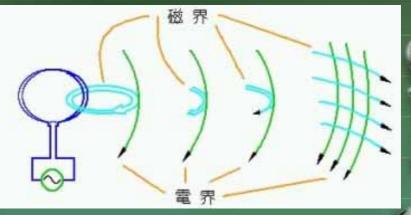
$$Z_{w} = \frac{|\vec{E}_{t}|}{|\vec{H}_{t}|} \Leftrightarrow R = \frac{V}{I}$$

E-field SE(dB)=20 $\log_{10}(E_1/E_2)$ H-field SE(dB)=20 $\log_{10}(H_1/H_2)$

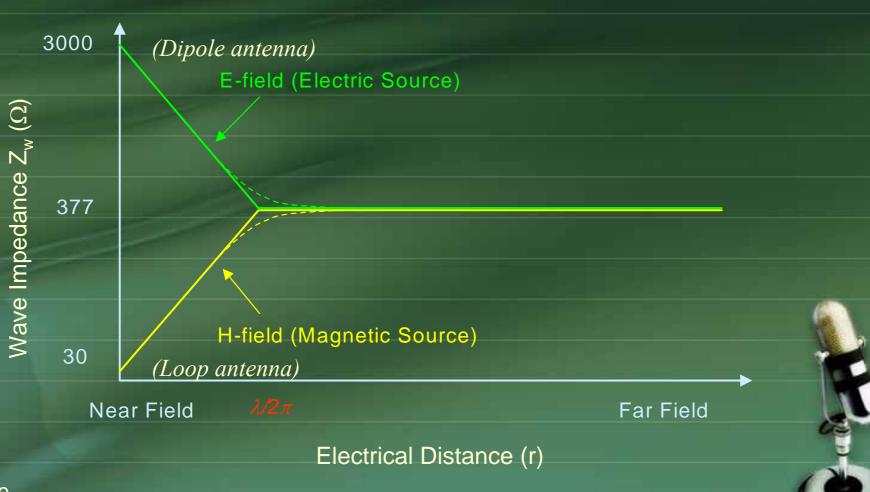
- Field characteristics are determined by the source, the media surrounding the source, and the distance between the source and the point observed.
- Near (Induction) field
 - For a high current and low voltage source (like a loop antenna), the near field is predominantly magnetic.
 - For a low current and high voltage source (like a rod or straight antenna), the near field is predominantly electric.
- Far (Radiation) field
 - The wave impedance equals the characteristic impedance of the medium (e.g. 377Ω for air)
 - Magnetic and electric effects don't need to concern separately.













Circuit Analysis Practical Model of Component and **Frequency Response** Capacitor Inductor Common mode and Differential mode Near Field and Far Field Antenna Effect Transmission Line Analysis

Antenna Effect

If the length of a cable is longer than $\lambda/4$ it can be seen as a good polar antenna.

As cables approach a <u>quarter-wavelength</u> in length, some of the current in the cable is out of phase. When the cable is a <u>half-wavelength</u> long the out-of-phase currents will cause the external coupling to be zero due to *cancellation* of effects.



Antenna Effect

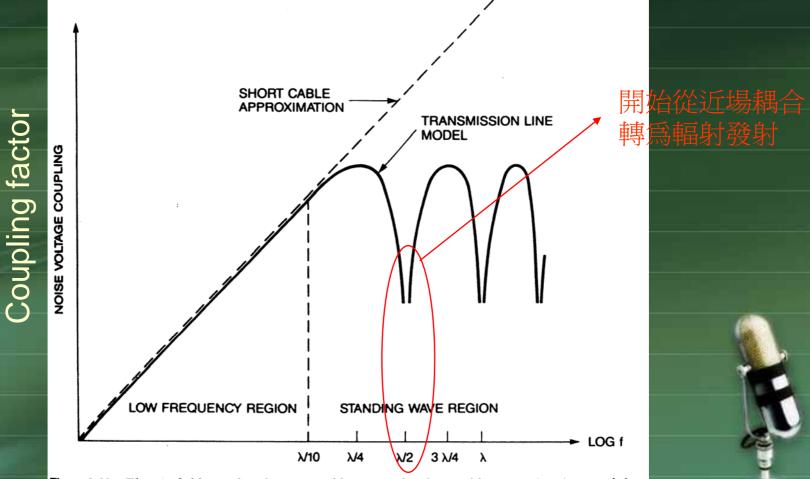


Figure 2-39. Electric field coupling between cables using the short cable approximations and the transmission line model.

2-32

Agenda

Circuit Analysis Practical Model of Component and **Frequency Response** Common mode and Differential mode Near Field and Far Field Antenna Effect Transmission Line Analysis Transmission Line Model Transfer Impedance Characteristic Impedance Reflection

Transmission Line Model

If $L \le \frac{1}{6} \cdot t_r$, lumped model is used ([4], p8) If $L > \frac{1}{6} \cdot t_r$, distributed model is used

- L : *Electrical line length* ; it is the time that a electron spends on running through a lead (pico-sec)
- tr : Rising time of the signal transmitting on the lead

Furthermore,

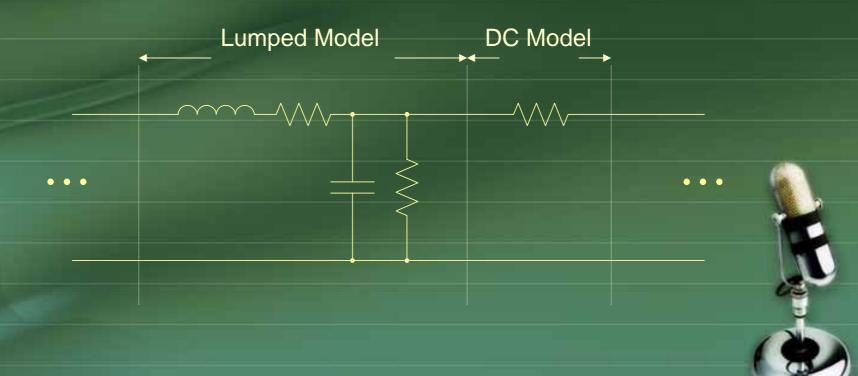
$$L = \frac{t_r \cdot V_p}{8}, \qquad V_p = \frac{C}{\sqrt{\varepsilon_r}}$$

 V_P : Propagation velocity C : 3x10⁸ m/s, ε_r : dielectric constant= $\varepsilon/\varepsilon_o$



Transmission Line Model Lumped Model

Delay for entire line << Signal transition time
 Every point on the transmission line can be seen with the same voltage potential.

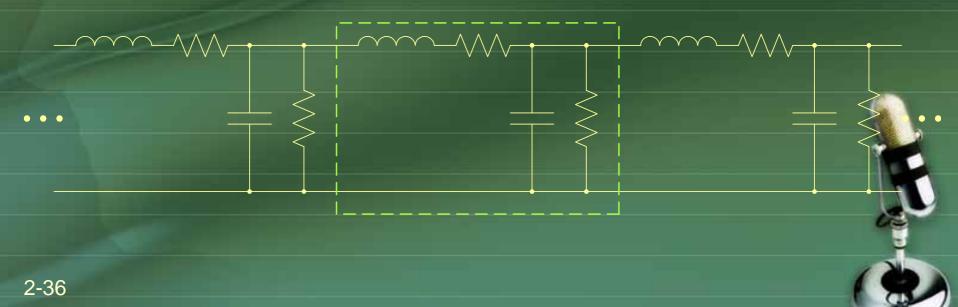




Transmission Line Model Distributed Model

Delay per section << Signal transition time
 Every point on the transmission line should be

- seen as a point with different voltage potential.
- Ringing, overshoot, reflection, and crosstalk will be more serious in the condition.



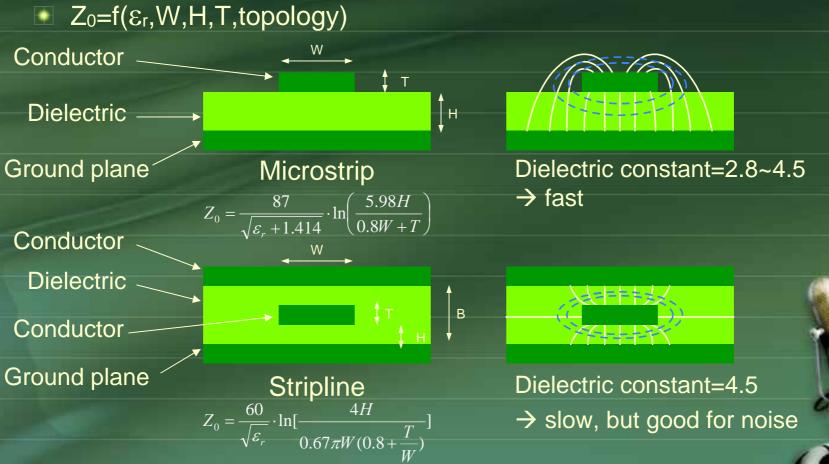
Transmission Line Model

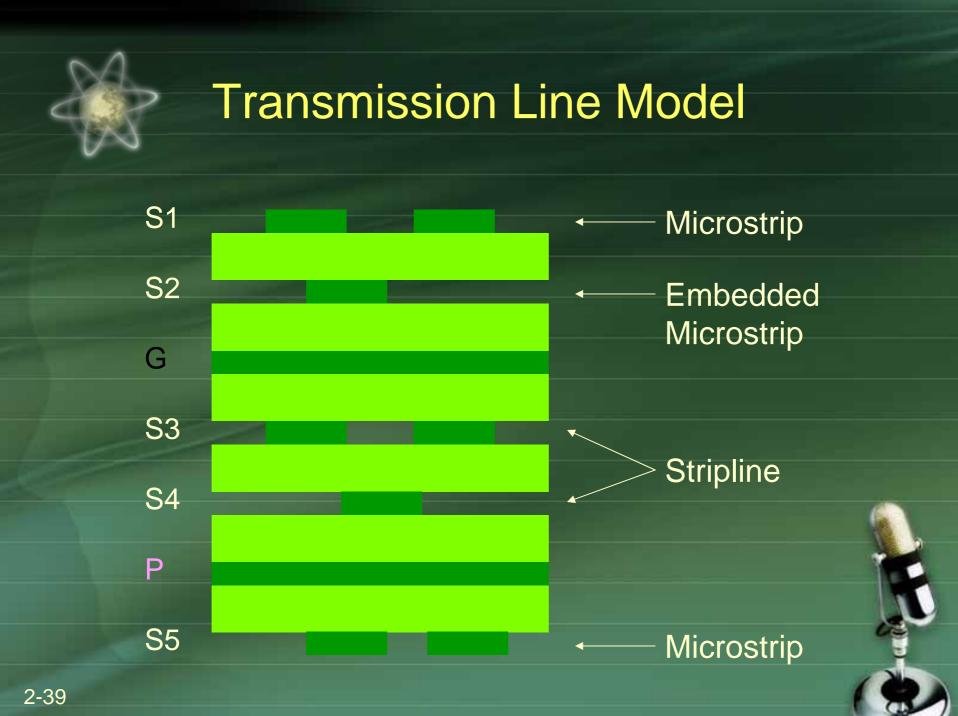
Keeping design within the DC-modeled or lumpmodeled region as far as possible is the key point. Traces (wires) of critical signals, such as clock sources, should be as short as possible Rising time and falling time of the fastest frequency signal in a circuitry should be as slow as possible. The lead running high frequency should have small propagation delay (ε_r is small). Circuitry and components should be scale down.

Transmission Line Model

ross sections of popular transmission line geometries

Transmission line – two conductors ([4], p.140,187)







Transmission Line Model

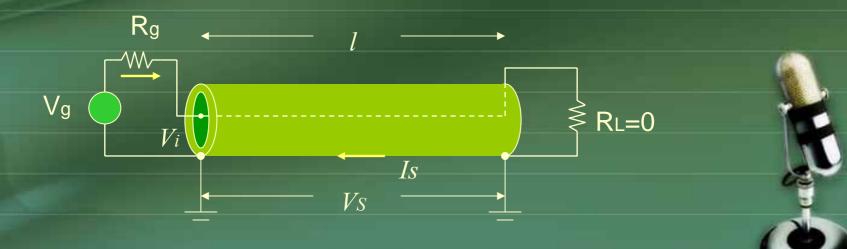
Dielectric material	Propagation delay(ps/in.)	Dielectric constant ϵ_r
Air	85	1.0
Coaxial cable(75%)	113	1.8
Coaxial cable(66%)	129	2.3
FR-4 PCB, outer conductor	140 ~ 180	2.8 ~ 4.5
FR-4 PCB, inner conductor	180	4.5
AI PCB, inner conductor	240 ~270	8 ~ 10

Transfer Impedance

The transfer impedance of a cable shield :

$$Z_t = \frac{V_S}{I_S} = \frac{1}{I_S} \left(\frac{dV_i}{dl}\right) \quad (\Omega/m)$$

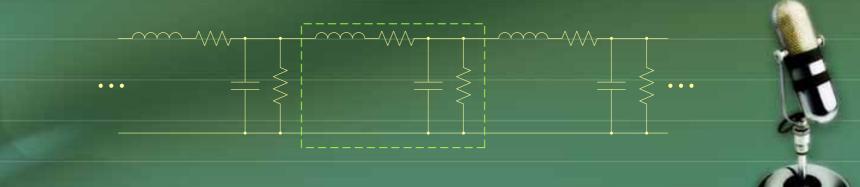
The shielding effectiveness of a cable can be expressed in terms of the shield transfer impedance.Lower Zt results from a better shielding.



Characteristic Impedance

The characteristic impedance of an *ideal* transmission line : $Z_0 = \sqrt{\frac{L}{C}}$ It is a constant.

- The characteristic impedance of an *practical* transmission line : it is a function with frequency.
 - Z₀ can be defined as the ratio of voltage to current while a high-frequency current is flowing on the transmission line.





All substrate FR-4 ; ε_r =4.5 , Z₀ accuracy ±30%





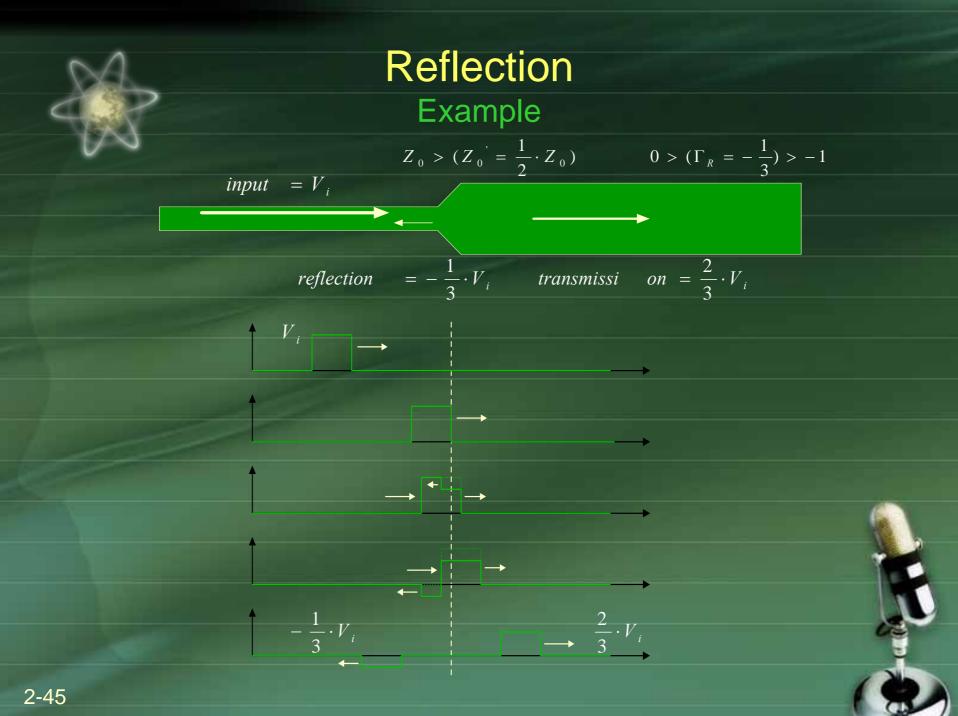
Reflection

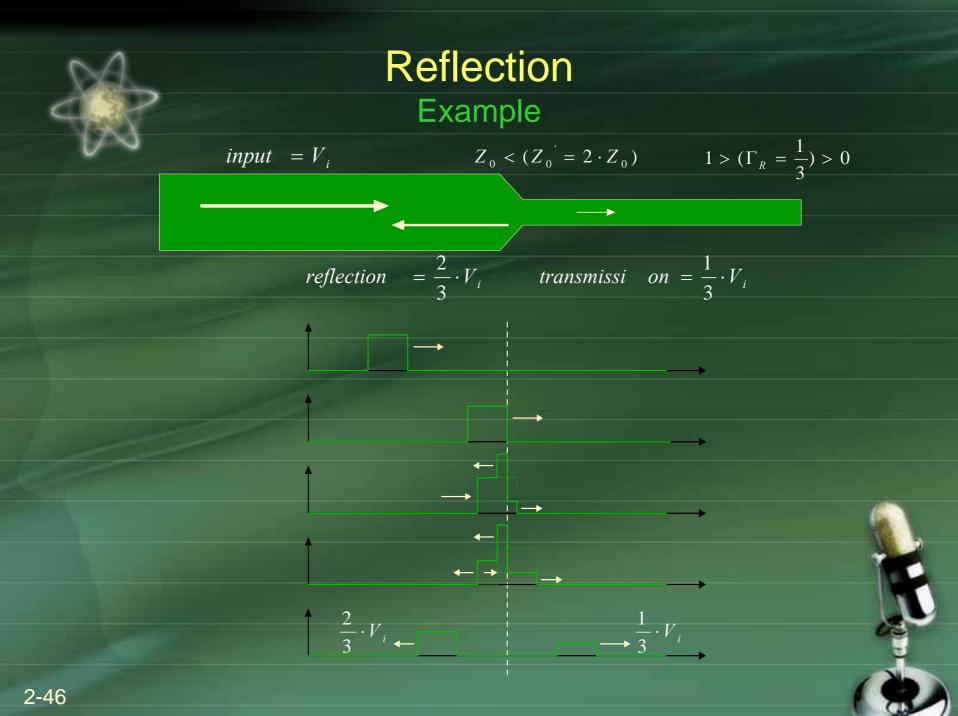
Reflection coefficient :

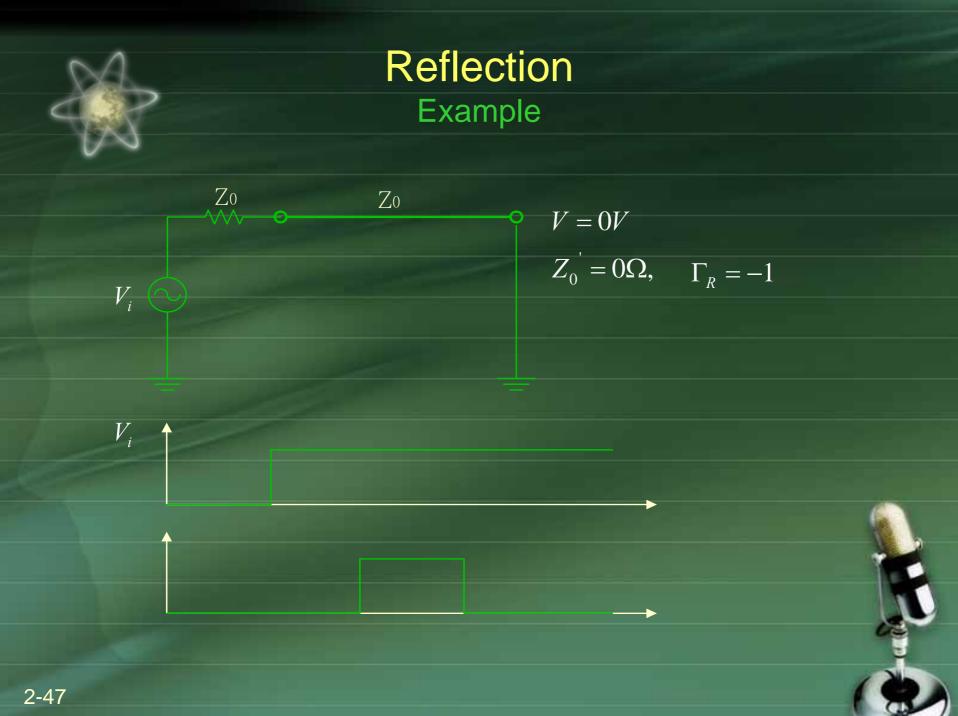
$$\Gamma_R = \frac{Z_r - Z_0}{Z_r + Z_0}$$

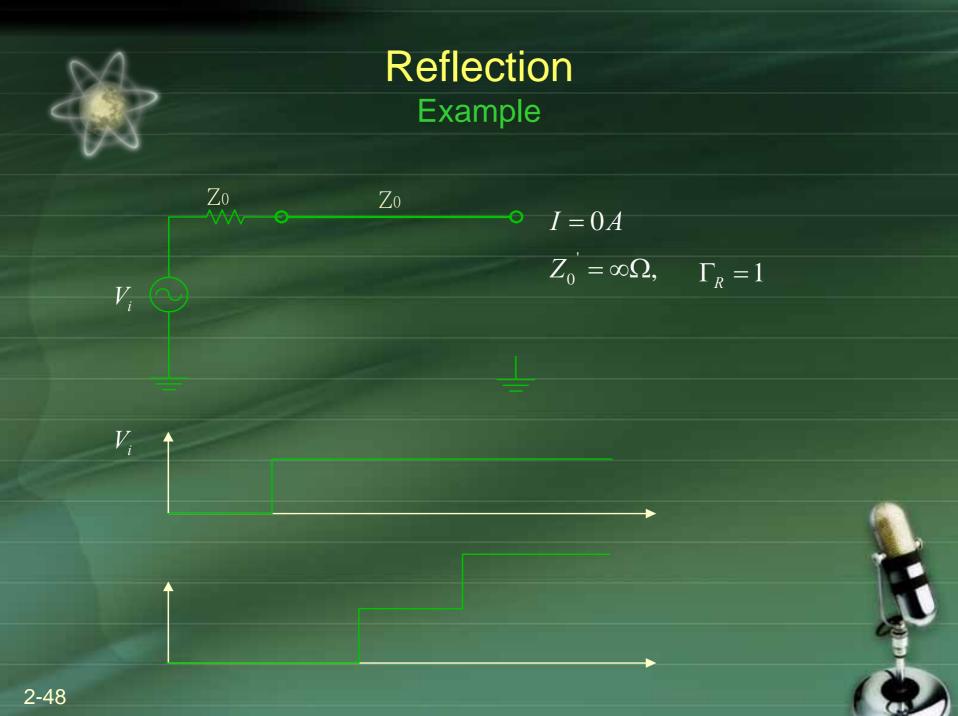
 Z_r : characteristic impedance of termination Z_0 : characteristic impedance of transmission line

Reflected signal = input signal $x \Gamma_R$









Reflection

Low-speed circuit : $2 \cdot T_{pd} < t_r, t_f$

Reflections are masked by rising/falling edges -- insignificant

